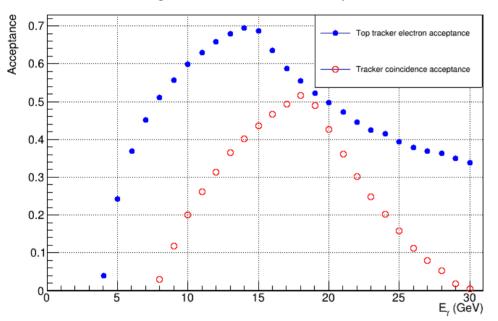
# Pair Spectrometer Tracker Hit Densities

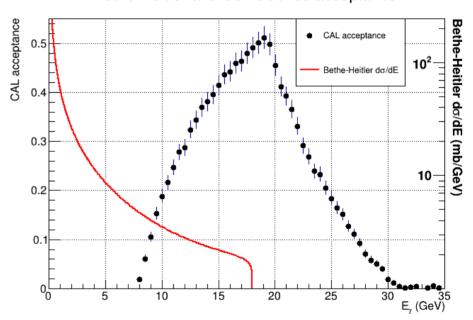
- To help decide which silicon sensor technology to use, we need to know how many electrons / pixel / sec are expected at the tracking planes.
- In particular, the sensor signal integration time is important to consider. Bunch crossings occur every 10 nsec at peak luminosities.

## Tracker Acceptances

#### Single and Coincidence Acceptances



#### Bethe-Heitler and Coincidence acceptance



### Math to calculate hit densities from the simulation

ep 275 GeV x 18 GeV

$$\sigma_{eff} = \int BH(E) \times A(E) dE = 25.5 \text{ mb (singles in top tracker)} = 7.6 \text{ mb (coincidence)}$$

Use "singles" to assess sensor occupancy.

I generate 10,000 events with 1 photon each. 5,212 detected singles ( $N_{\text{singles}}$ )

The photon energy is sampled according to the Bethe-Heitler spectrum.

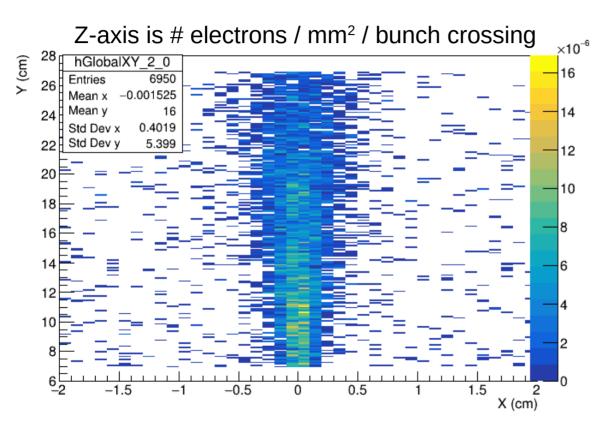
For convenience, Emin = 5 GeV.

The number of observed electrons in the top tracker is used to find the effective "time window" of the simulation,  $T_{\text{eff}}$ .

Conversion probability = 0.01 
$$N_{singles} = f imes \mathcal{L} imes \sigma_{eff} imes T_{eff}$$
  $T_{eff} = 13 imes 10^{-3} sec$ 

This is to be used to normalize the spatial hit density in my particular simulation.

### Electron hit density in top tracking planes



- For ep 275x18, we have at most ~16e-6 electrons / mm² / bunch Xing
- Highest rate is for eA 110x10, which is ~x20 higher = 3e-4 electrons / mm² / bunch Xing
- Pixels sizes are generally smaller than 1mm<sup>2</sup>
- Beam effects will further dilute the hit density

Critical time = 1 / Z-axis, is the integration time that gives 1 electron per pixel (pileup begins).

	ACLGAD pixel size: 500 µm	Tower Jazz HV- MAPS: pixel size: 36 µm
Critical time	1.3e4 bunch Xings = 133 µsec	2.6e6 bunch Xings = 26 millisec

Extremely low occupancy.

Would MAPS sensors be sufficient? Pros: very low material budget.